General Purpose Amplifier Transistor

NPN Silicon Surface Mount

This NPN Silicon Epitaxial Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- High h_{FE}, 210 460
- Low $V_{CE(sat)}$, < 0.5 V
- Moisture Sensitivity Level 1
- ESD Protection: Human Body Model > 4000 V Machine Model > 400 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	60	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	7.0	Vdc
Collector Current - Continuous	I _C	100	mAdc
Collector Current - Peak	I _{C(P)}	200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 1)	P _D	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

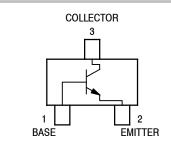
 Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

1



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SC-70 (SOT-323) CASE 419 STYLE 3

MARKING DIAGRAM



ZR = Device Code

M = Date Code*

Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending
upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MSD1819A-RT1G	SC-70/ SOT-323 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage (I _C = 2.0 mAdc, I _B = 0)	V _{(BR)CEO}	50	-	Vdc
Collector-Base Breakdown Voltage (I _C = 10 μAdc, I _E = 0)	V _{(BR)CBO}	60	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = 10 \mu Adc, I_E = 0$)	V _{(BR)EBO}	7.0	-	Vdc
Collector-Base Cutoff Current (V _{CB} = 20 Vdc, I _E = 0)	I _{CBO}	-	0.1	μΑ
Collector-Emitter Cutoff Current (V _{CE} = 10 Vdc, I _B = 0)	I _{CEO}	-	0.1	μΑ
DC Current Gain (Note 2) $ (V_{CE} = 10 \text{ Vdc}, I_C = 2.0 \text{ mAdc}) $ $ (V_{CE} = 2.0 \text{ Vdc}, I_C = 100 \text{ mAdc}) $	h _{FE1} h _{FE2}	210 90	340 -	-
Collector-Emitter Saturation Voltage (Note 2) (I _C = 100 mAdc, I _B = 10 mAdc)	V _{CE(sat)}	-	0.5	Vdc

^{2.} Pulse Test: Pulse Width ≤ 300 μs, D.C. ≤ 2%.

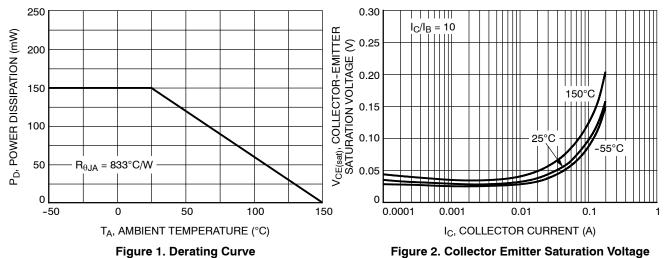


Figure 1. Derating Curve

h_{FE}, DC CURRENT GAIN

vs. Collector Current 450 150°C (10 V) $V_{\text{BE}(\text{sat})}$, BASE-EMITTER SATURATION VOLTAGE (V) 0.95 $I_C/I_B = 10$ 400 150°C (2 V) 0.85 350 300 0.75 25°C (10 V) 250 0.65 25°C (2 V) 150°C 200 0.55 -55°C (10 V) 150 -55°C (2 V) 0.45 100 0.35 50 0.25 0.0001 0.001 0.0001 0.01 0.1 0.001 0.01 0.1 I_C, COLLECTOR CURRENT (A) IC, COLLECTOR CURRENT (A)

Figure 3. DC Current Gain vs. Collector Current

Figure 4. Base Emitter Saturation Voltage vs. **Collector Current**

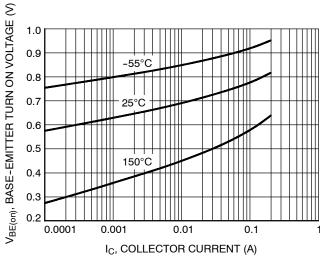


Figure 5. Base Emitter Turn-On Voltage vs.
Collector Current

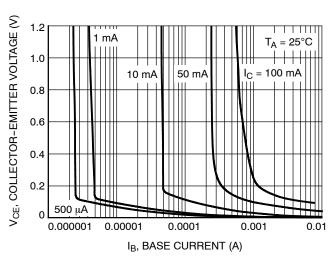


Figure 6. Collector Saturation Region

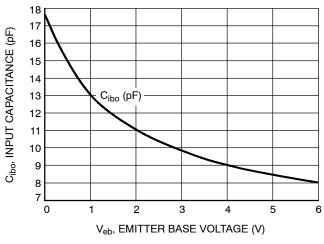


Figure 7. Input Capacitance

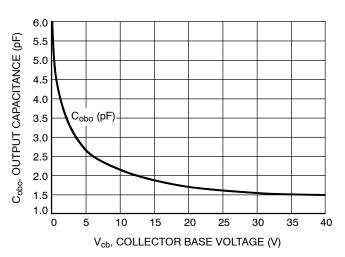
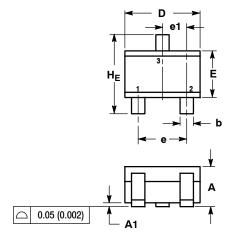


Figure 8. Output Capacitance

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.

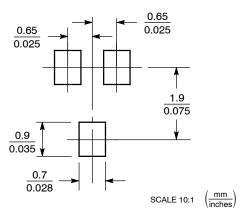
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2		0.70 REF			0.028 REF	=
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1		0.65 BSC			0.026 BSC	
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

STYLE 3

PIN 1. BASE 2. EMITTER

3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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